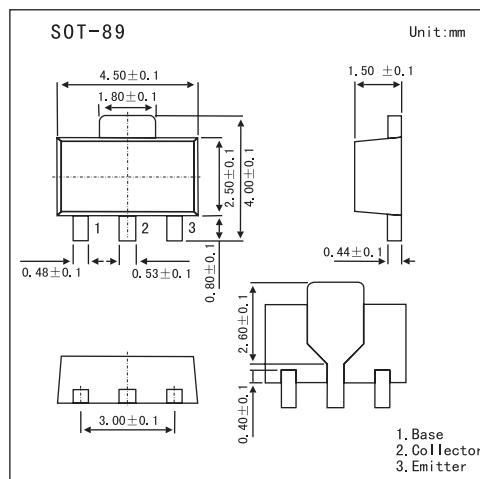


# 2SC2982

## Features

- Low Saturation Voltage  
:  $V_{CE(sat)} = 0.5V$  (max) ( $I_C = 2A, I_B = 50mA$ )
- Small Flat Package
- Complementary to 2SA1314



## Absolute Maximum Ratings $T_a = 25^\circ C$

Parameter	Symbol	Rating	Unit
Collector-Base Voltage	$V_{CBO}$	20	V
Collector-Emitter Voltage	$V_{CEO}$	10	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Collector Current (DC)	$I_C$	2	A
Collector Current (Pulsed) *1	$I_{CP}$	4	A
Base Current (DC)	$I_B$	0.4	A
Base Current (Pulse) *1	$I_{BP}$	0.8	A
Collector Power Dissipation	$P_C$	500	mW
	$P_C$ *2	1000	
Junction temperature	$T_j$	150	$^\circ C$
Storage temperature Range	$T_{stg}$	-55 to +150	$^\circ C$

\*1 Pulse test: pulse width = 10ms (max), duty cycle = 30% (max)

\*2 Mounted on a ceramic substrate (250 mm<sup>2</sup> x 0.8 t)

## Electrical Characteristics $T_a = 25^\circ C$

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Collector Cut-off Current	$I_{CBO}$	$V_{CB} = 30V, I_E = 0$			0.1	$\mu A$
Emitter Cut-off Current	$I_{EBO}$	$V_{EB} = 6V, I_C = 0$			0.1	$\mu A$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 10mA, I_B = 0$	10			V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 1mA, I_C = 0$	6			V
DC Current Gain	$h_{FE}$	$V_{CE} = 1V, I_C = 0.5A$	140		600	
		$V_{CE} = 1V, I_C = 2A$	70	140		
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 2A, I_B = 50mA$		0.2	0.5	V
Base-Emitter Voltage	$V_{BE}$	$V_{CE} = 1V, I_C = 2A$		0.86	1.5	V
Transition Frequency	$f_T$	$V_{CE} = 1V, I_C = 0.5A$		150		MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB} = 10V, I_E = 0, f = 1MHz$		27		pF



# 2SC2982

## hFE Classification

Marking	S			
Rank	A	B	C	D
hFE	140 ~ 240	200 ~ 330	300 ~ 450	420 ~ 600

## Electrical Characteristics Curves

